

34mm Module


 $V_{CES}=1200V, I_{C\ nom}=200A$
二极管，逆变器 / Diode, Inverter

最大额定值 / Maximum Ratings

Parameter	Conditions	Symbol	Value	Unit
重复峰值额定电压 Repetitive peak normal voltage	$T_{vj}=25^{\circ}C$	V_{Fnorm}	1200	V
反向重复峰值电压 Repetitive peak reverse voltage	$T_{vj}=25^{\circ}C$	V_{RRM}	1350	V
连续正向直流电流 Continuous DC forward current		I_F	200	A
正向重复峰值电流 Repetitive peak forward current	$t_p=1ms$	I_{FRM}	400	A
正向非重复峰值浪涌电流 Surge Non-repetitive forward current	$t_p=10ms, \sin 180^{\circ}, T_j=25^{\circ}C$	I_{FSM}	1600	A
I^2t 值 I^2t -value	$t_p=10ms, \sin 180^{\circ}, T_j=25^{\circ}C$	I^2t	13000	A ² S

特征值 / Characteristic Values

Parameter	Conditions	Symbol	Value			Unit
			Min.	Typ.	Max.	
正向电压 Forward voltage	$I_F=200A$ $I_F=200A$ $I_F=200A$	$T_{vj}=25^{\circ}C$ $T_{vj}=125^{\circ}C$ $T_{vj}=150^{\circ}C$	V_F	2.07 2.28 2.24	2.50 2.80 2.80	V
反向漏电流 Reverse Leakage Current	$V_{RRM}=1200V$	$T_{vj}=25^{\circ}C$	I_R		1.0	mA
反向恢复峰值电流 Peak reverse recovery current	$I_F=200A,$ $-di_F/dt=1700A/\mu s(T_{vj}=150^{\circ}C)$ $V_R=600V, R_g=3.3\ \Omega$	$T_{vj}=25^{\circ}C$ $T_{vj}=125^{\circ}C$ $T_{vj}=150^{\circ}C$	I_{RM}	96 122 125		A
恢复电荷 Recovered charge	$I_F=200A,$ $-di_F/dt=1700A/\mu s(T_{vj}=150^{\circ}C)$ $V_R=600V, R_g=3.3\ \Omega$	$T_{vj}=25^{\circ}C$ $T_{vj}=125^{\circ}C$ $T_{vj}=150^{\circ}C$	Q_r	21.64 41.26 44.24		μC

反向恢复损耗（每脉冲） Reverse recovered energy	$I_F=200A$, $-di_F/dt=1700A/\mu s(T_{vj}=150^\circ C)$ $V_R=600V, R_g=3.3 \Omega$	$T_{vj}=25^\circ C$ $T_{vj}=125^\circ C$ $T_{vj}=150^\circ C$	E_{rec}		8.97 18.72 19.26		mJ
反向恢复时间 Reverse recovered time	$I_F=200A$, $-di_F/dt=1700A/\mu s(T_{vj}=150^\circ C)$ $V_R=600V, R_g=3.3 \Omega$	$T_{vj}=25^\circ C$ $T_{vj}=125^\circ C$ $T_{vj}=150^\circ C$	T_{rr}		659 922 971		ns
软度系数 Soft factor	$I_F=200A$, $-di_F/dt=1700A/\mu s(T_{vj}=150^\circ C)$ $V_R=600V, R_g=3.3 \Omega$	$T_{vj}=25^\circ C$ $T_{vj}=125^\circ C$ $T_{vj}=150^\circ C$	Soft		6.5 7.5 8.0		
结-外壳热阻 Thermal resistance, junction to case	每个二极管 / per diode		R_{thJC}			0.19	K/W
外壳-散热器热阻 Thermal resistance, case to heat sink	每个二极管 / per FRD $\lambda_{grease} = 1.09$ W/(m·K)		R_{thCH}			0.12	K/W
在开关状态下温度 Temperature under switching conditions			$T_{vj op}$	-40		150	$^\circ C$

模块 / Module

Parameter	Conditions	Symbol	Value			Unit
绝缘测试电压 Isolation test voltage	RMS, $f=50Hz$, $t=1min$	V_{ISOL}	4000			V
内部绝缘 Internal isolation			Al ₂ O ₃			
储存温度 Storage temperature		T_{stg}	-40		125	$^\circ C$
模块安装的扭矩 Mounting torque for modul mounting	M6, 螺丝	M	3.0		5.0	Nm
端子连接扭矩 Terminal Connection Torque	M5, 螺丝	M	2.5		5.0	Nm
重量 Weight		W		145		g

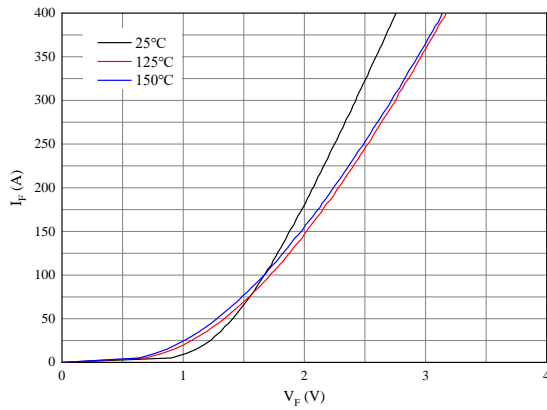


图 1. 正向偏压特性 二极管
Figure1: Forward characteristic of Diode

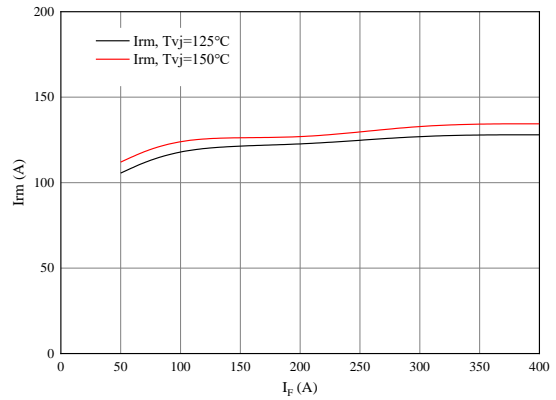


图 2. 反向恢复峰值电流
Figure2: Peak reverse recovery current
VCE=600V, Rg=3.3 Ω

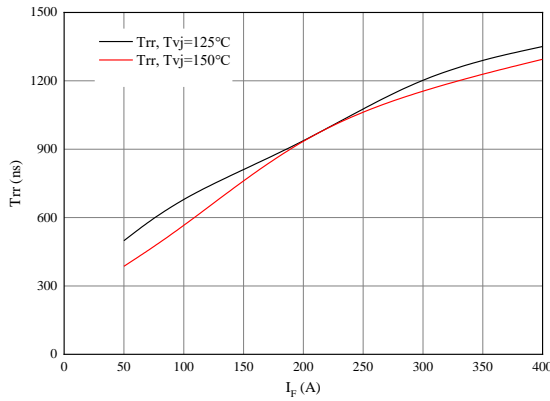


图 3. 反向恢复时间
Figure3: Reverse recovered time
VCE=600V, Rg=3.3 Ω

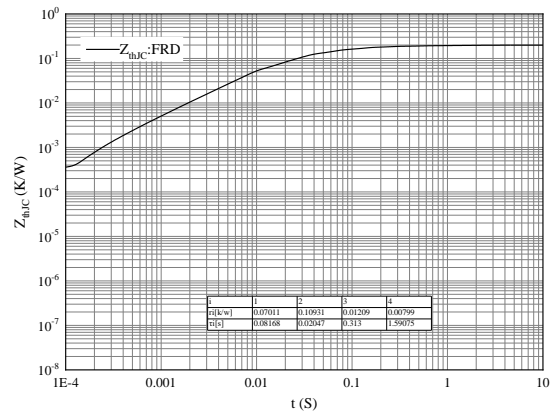
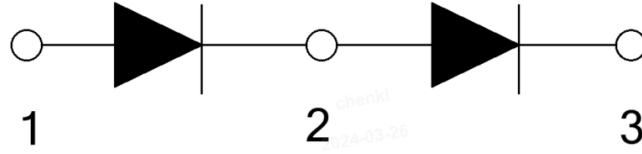


图 4. 瞬态热阻抗 FRD 逆变器
Figure11. Transient thermal impedance FRD ,Inverter
 $Z_{thJC}=f(t)$

接线图 / Circuit diagram



封装尺寸 / Package outlines

